

**Erratum: "Picosecond large-signal switching characteristics of a pseudomorphic AlGaAs/InGaAs modulation-doped field-effect transistor" [Appl. Phys. Lett. 61, 1187 (1992)]**

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The correct title of the article is given above.

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**Erratum: "Uniform and flexible 24-meter superconducting tape of silver-sheathed  $Tl_{0.5}Pb_{0.5}Ba_{0.4}Sr_{1.6}Ca_2Cu_3O_{8.2}$ " [Appl. Phys. Lett. 61, 1715 (1992)]**

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The criterion of  $\Delta V=1$  mV printed twice in the text and also in the caption of Fig. 3 should be  $\Delta V=1$   $\mu V$ .